

High Voltage Fast-Switching NPN Power Transistor

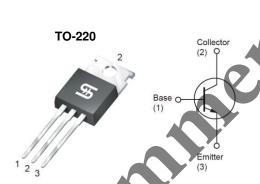
FEATURES

- High Voltage Capability
- Fast Switching Speed
- Pb-free plating
- RoHS compliant

APPLICATION

- Electronic Ballast
- Switch mode power supply

KEY PERFORMANCE PARAMETERS				
PARAMETER		VALUE	UNIT	
BV _{CEO}		420	V	
BV_{CBO}		1050	V	
I _C		5	Α	
V _{CE(SAT)}	I _C =1A, I _B =0.2A	0.5	V	



Notes: Moisture sensitivity level: level 3. Per J-STD-020

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)				
PARAMETER	SYMBOL	LIMIT	UNIT	
Collector-Base Voltage	V _{CBO}	1050	V	
Collector-Emitter Voltage @ V _{BE} =0V	V _{CES}	420	V	
Emitter-Base Voltage	V_{EBO}	15	V	
Collector Current	I _C	5	Α	
Collector Peak Current (tp <5ms)	I _{CM}	8	Α	
Base Current	I _B	2	Α	
Base Peak Current (tp <5ms)	I _{BM}	4	Α	
Power Total Dissipation @ T _A =25°C	P _{DTOT}	70	W	
Maximum Operating Junction Temperature	T _J	+150	°C	
Storage Temperature Range	T _{STG}	-55 to +150	°C	

THERMAL PERFORMANCE				
PARAMETER	SYMBOL	LIMIT	UNIT	
Junction to Case Thermal Resistance	R _{eJC}	1.8	°C/W	
Junction to Ambient Thermal Resistance	R _{eJA}	62.5	°C/W	





ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Collector-Base Voltage	I _C =0.5mA	BV _{CBO}	1050			V
Collector-Emitter Breakdown Voltage	I _C =5mA	BV _{CEO}	420			V
Emitter-Base Breakdown Voltage	I _E =1mA	BV _{EBO}	15			V
Collector Cutoff Current	$V_{CE} = 400 V, I_{B} = 0$	I _{CEO}		10	250	μΑ
Collector Cutoff Current	$V_{CB} = 950V, I_{E} = 0$	I _{CBO}			10	μΑ
Collector-Emitter Saturation Voltage	$I_{C}=1A$, $I_{B}=0.2A$	V _{CE(SAT)} 1		0.15	0.5	٧
Collector-Emitter Saturation Voltage	I _C =3.5A, I _B =1A	V _{CE(SAT)} 2		1.2	1.5	V
Base-Emitter Saturation Voltage	I_{C} =3.5A, I_{B} =1A	V _{BE(SAT)} 1	7	1.0	1.5	V
DO Owner I Oak	$V_{CE} = 5V, I_{C} = 0.1A$	h _{FE} 1	48	70	100	
DC Current Gain	$V_{CE} = 3V, I_{C} = 0.8A$	h _{FE} 2	23	28	50	
Rise Time (Note 2)		t _r			1	μs
Storage Time (Note 2)	V _{CC} =5V, I _C =0.5A	t _{stg}	4.5	5	5.5	μs
Fall Time (Note 2)		t _f			1.2	μs
Repetitive Avalanche Energy	L=2mH	E _{AR}	6			mJ

Notes:

- 1. Pulse test: ≤380µs, duty cycle ≤ 2%
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 For DESIGN AID ONLY, not subject to production testing.



ORDERING INFORMATION

PART NO.	PACKAGE	PACKING
TSC742CZ C0	TO-220	50pcs / Tube

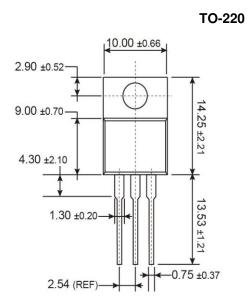
Note:

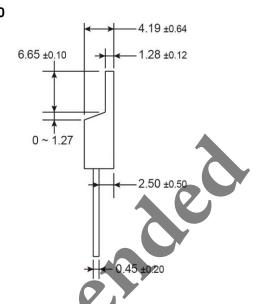
1. Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC





PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)





Marking Diagram



Y = Year Code

M = Month Code for Halogen Free Product

A =Jan B =Feb

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C =Mar D =Apr

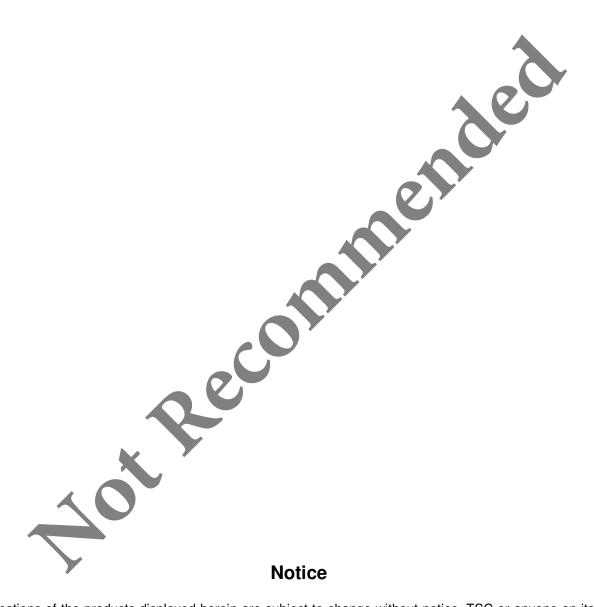
E =May F =Jun

G =Jul H ∍Aug

I =Sep J =Oct |

K ≠Nov L =Dec

L = Lot Code (1~9, A~Z)



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